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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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Title:

**NON-VOLATILE MEMORY CELL COMPRISING
DIELECTRIC LAYERS HAVING A LOW DIELECTRIC
CONSTANT AND CORRESPONDING MANUFACTURING
PROCESS**

Application No.: 10/749,130

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Examiner/ Unit: Dana Farahani/2891

Attorney Docket No.: 2110-099-03

CERTIFICATE OF MAILING OR TRANSMISSION

I hereby certify that this correspondence is being deposited in the United States Postal Service as First Class mail in an envelope addressed to: MS Amendments, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on this 6th day of August, 2007.

Signature

AMENDMENT AND RESPONSE UNDER 37 CFR §1.111

TO THE COMMISSIONER FOR PATENTS

Reconsideration of the above-referenced patent application is requested in view of the following amendments and remarks. Amendments to the specification are set forth beginning on page 2 of this paper while amendments to the claims are reflected in the listing of claims which begins on page 4 of this paper. Remarks in response to the Final Office Action mailed June 6, 2007 are set forth beginning on page 9 of this paper.